TLP504A, TLP504A-2

TOSHIBA Photocoupler IRED & Photo-Transistor

TLP504A, TLP504A-2

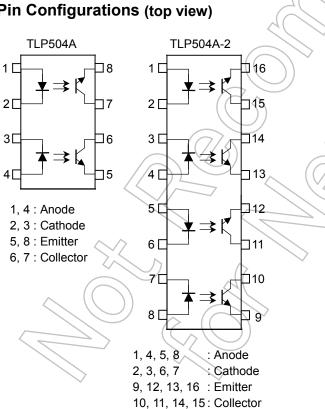
Programmable Controllers AC/DC-Input Module Solid State Relay

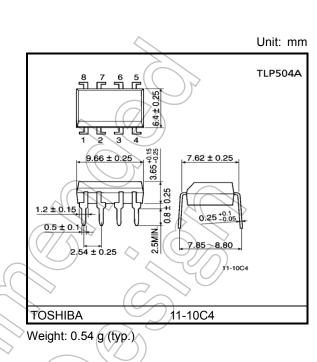
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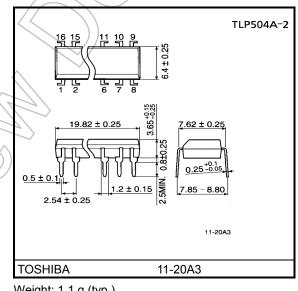
The TOSHIBA TLP504A and TLP504A-2 consists of a phototransistor optically coupled to an infrared emitting diode. The TLP504A offers two isolated channels in an eight lead plastic DIP package, while the TLP504A-2 provides four isolated channels in a sixteen plastic DIP package.

- Collector-emitter voltage: 55 V (min)
- Current transfer ratio: 50% (min) Rank GB: 100% (min)
- Isolation voltage: 2500 Vrms (min)
- UL-recognized: UL 1577, File No.E67349









Weight: 1.1 g (typ.)

Start of commercial production 1981-01

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		O male al	Ra	1.1-24		
	Characteristics	Symbol	TLP504A	TLP504A-2	Unit	
	Forward current	١ _F	60	60 50		
	Forward current derating	ΔI _F /°C	-0.7 (Ta ≥ 39°C) -0.5 (Ta ≥ 25°C)		mA/°C	
	Pulse forward current (100µs pulse, 100pps)	IFP		1	А	
LED	Reverse voltage	VR		5	V Y	
	Diode power dissipation	PD	1	00	mW	
	Diode power dissipation derating	∆P _D /°C	-1.2 (Ta ≥ 39°C)	-1.0 (Ta ≥ 25°C)	mW/°C	
	Junction temperature	Tj	1	°C		
	Collector-emitter voltage	VCEO	Ę	55	V	
	Emitter-collector voltage	V _{ECO}	.(X		
٦	Collector current	IC		mA		
Detector	Collector power dissipation (1 circuit)	PC	150	100	mW	
	Collector power dissipation derating (1 circuit) (Ta \ge 25°C)	ΔP _C /°C	-1.5	-1.0	mW/°C	
	Junction temperature	Тј		25	°C	
Sto	rage temperature range	T _{stg}	-55 t	o 150	°C	
Ope	erating temperature range	T _{opr}	-55 t	°C		
Lea	d soldering temperature (10 s)	Tsol	2	60	°C	
Total package power dissipation		RT	250	150	mW	
	al package power dissipation ating (Ta ≥ 25°C)	ΔΡτ/°C	-2.5	-1.5	mW/°C	
	ation voltage C, 60 s, R.H.≤ 60 %) (Note 1)	BVS	2500		Vrms	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Device considered a two terminal device: LED side pins shorted together and detector side pins shorted together.

Recommended Operating Conditions

Characteristicss	Symbol	Min.	Тур.	Max.	Unit
Supply voltage	Vcc	—	5	24	V
Forward current	lF	—	16	20	mA
Collector current	IC	—	1	10	mA
Operating temperature	T _{opr}	-25		85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Electrical Characteristics (Ta = 25°C)

	Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
	Forward voltage	VF	I _F = 10 mA	1.0	1.15	1.3	V
LED	Reverse current	I _R	V _R = 5 V	_	_	10	μA
	Capacitance	Ст	V = 0 V, f = 1 MHz	X	30	_	pF
Detector	Collector-emitter breakdown voltage	V(BR)CEO	IC = 0.5 mA	55	-	_	V
	Emitter-collector breakdown voltage	V(BR)ECO	IE = 0.1 mA	Z)~_	_	V
	Collector dark current ICEO	1000	V _{CE} = 24 V	$\widetilde{\langle n \rangle}$	10	100	nA
		V _{CE} = 24 V, Ta = 85 °C)}	2	50	μA	
	Capacitance collector to emitter	CCE	V = 0 V, f = 1 MHz		10		pF

Coupled Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Current transfer ratio	I _C /I _F	IF = 5 mA, VCE = 5 V	50	40)	600	%
		Rank G	B 100	60	600 —	
Saturated CTR	IC/IF(sat)	Rank G	30		_	%
Collector-emitter	~	Ic = 2.4 mA, I _F = 8 mA) –	—	0.4	
saturation voltage	VCE(sat)	$I_{C} = 0.2 \text{ mA}, I_{F} = 1 \text{ mA}$		0.2	-	V
	(())	Rank G		—	0.4	

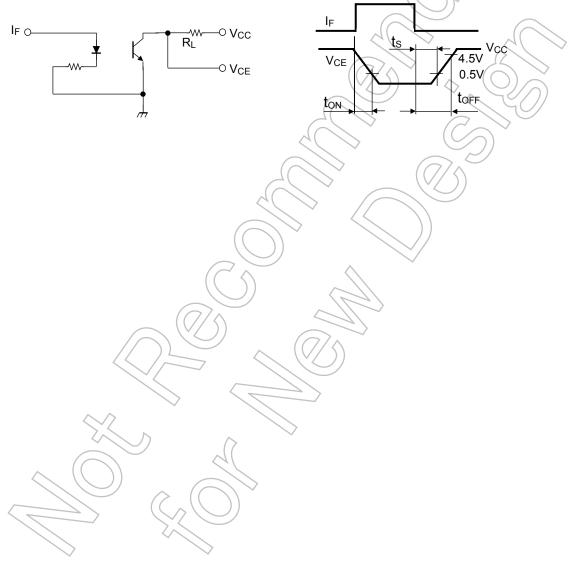
Isolation Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance input to output	Cs	Vs = 0 V, f = 1 MHz	_	0.8	_	pF
Isolation resistance	Rs	Vs = 500 V, R.H.≤ 60 %	5×10 ¹⁰	10 ¹⁴	_	Ω
Isolation voltage	BVs	AC, 60 s	2500		l	Vrms

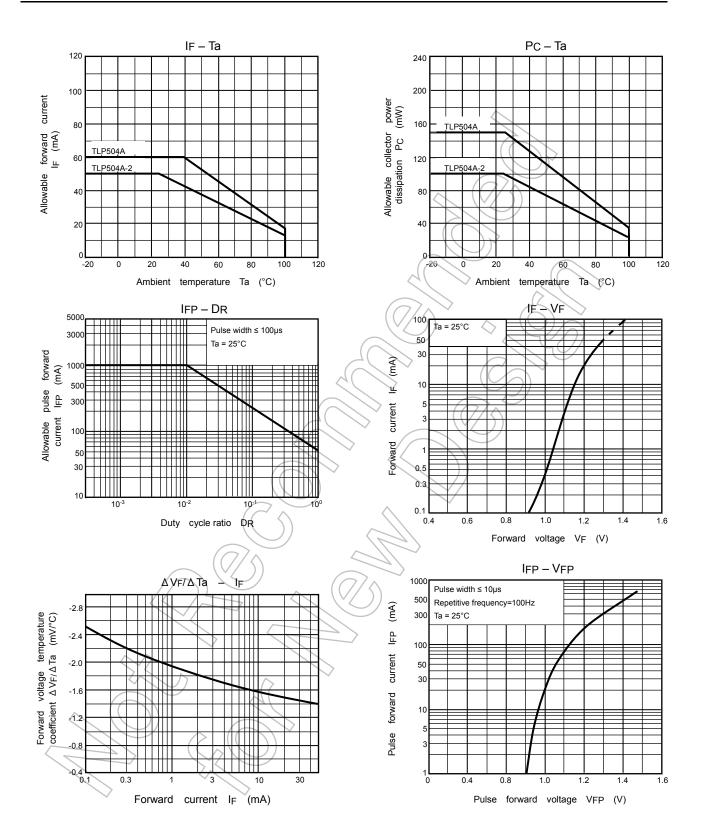
Switching Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Rise time	tr		_	2	_	
Fall time	t _f	V _{CC} = 10 V, I _C = 2 mA		3	_	
Turn-on time	ton	R _L = 100 Ω	/	3	_	μs
Turn-off time	toff		$\langle \rangle$	3	_	
Turn-on time	ton		(\mathcal{L})	2	_	
Storage time	ts	$R_L = 1.9 kΩ$ (Fig.1) V _{CC} = 5 V, I _F = 16 mA	\sum_{k}	15	_	μs
Turn-off time	toff		\mathcal{Y}	25		

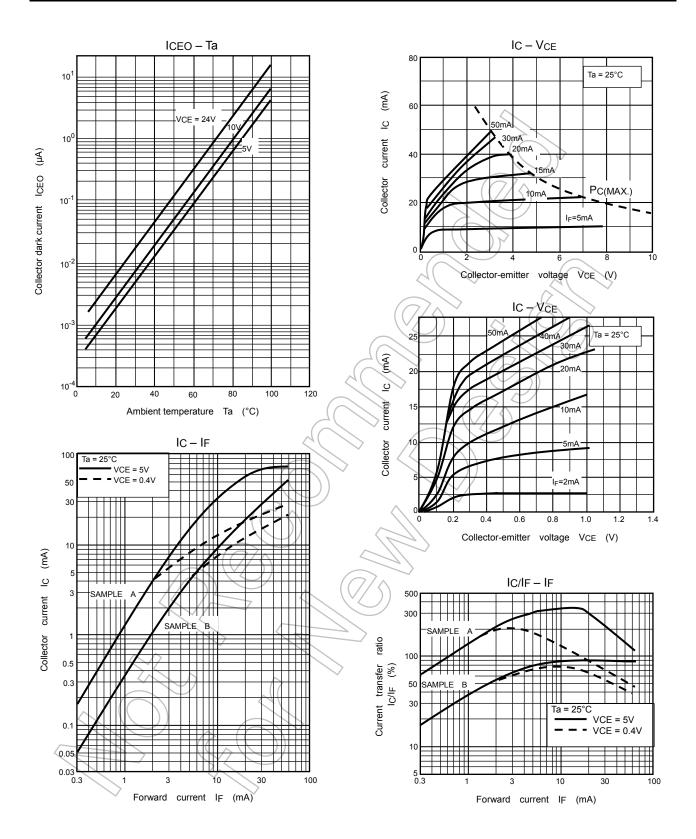
Fig. 1 Switching time test circuit



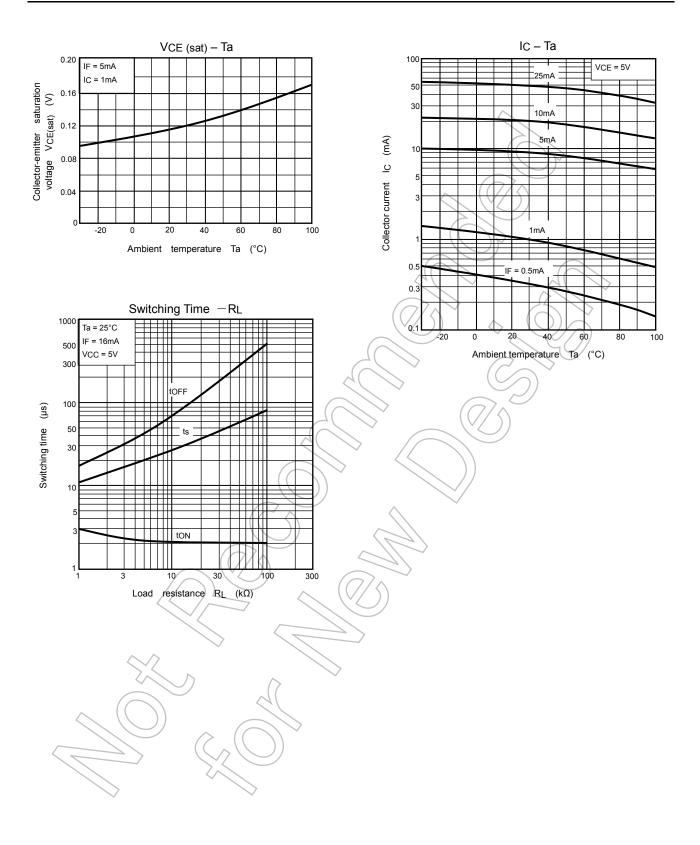
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